Product data sheet

1. General description

PNP low V_{CEsat} transistor in a medium power flat lead SOT89 plastic package.

NPN complement: PBSS4320X

2. Features and benefits

- SOT89 (SC-62) package
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability: I_C and I_{CM}
- · Higher efficiency leading to less heat generation
- · Reduced printed-circuit board requirements.
- AEC-Q101 qualified

3. Applications

- Power management
 - DC/DC converters
 - · Supply line switching
 - Battery charger
 - LCD backlighting.
- Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - · Inductive load driver (e.g. relays, buzzers and motors).

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|---|---|-----|-----|-----|-----|------|
| V _{CEO} | collector-emitter voltage | open base | | - | - | -20 | V |
| Ic | collector current | | [1] | - | - | -3 | Α |
| I _{CM} | peak collector current | limited by T _{j(max)} | | - | - | -5 | Α |
| h _{FE} | DC current gain | V _{CE} = -2 V; I _C = -0.1 A | | 220 | - | - | |
| R _{CEsat} | collector-emitter saturation resistance | I _C = -3 A; I _B = -300 mA | [2] | - | 90 | 105 | mΩ |

- [1] Device mounted on a ceramic printed-circuit board 7 cm², single-sided copper, tin-plated.
- [2] Pulsed test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$



20 V, 3 A PNP low VCEsat (BISS) transistor

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--------------------|----------------|
| 1 | E | emitter | | C - |
| 2 | С | collector | | В |
| 3 | В | base | 3 2 1 SOT89 | E sym132 |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PBSS5320X | SOT89 | plastic surface-mounted package; die pad for good heat transfer; 3 leads | SOT89 |

7. Marking

Table 4. Marking codes

| П | Type number | Marking code |
|---|-------------|--------------|
| Ī | PBSS5320X | S45 |

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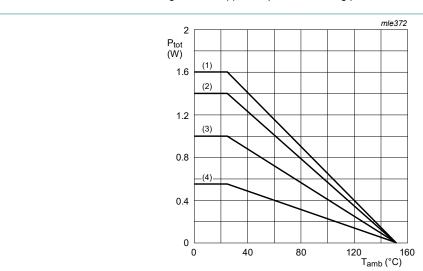
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|--------------------------------|-----|-----|------|------|
| V_{CBO} | collector-base voltage | open emitter | | - | -20 | V |
| V_{CEO} | collector-emitter voltage | open base | | - | -20 | V |
| V_{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| I _C | collector current | | [1] | - | -3 | А |
| I _{CM} | peak collector current | limited by T _{j(max)} | | - | -5 | А |
| I _B | base current | | | - | -0.5 | А |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [2] | - | 550 | mW |
| | | | [3] | - | 1 | W |
| | | | [4] | - | 1.4 | W |
| | | | [1] | - | 1.6 | W |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- Device mounted on a ceramic printed-circuit board 7 cm², single-sided copper, tin-plated.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm² [3]
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



- (1) Ceramic PCB; 7 cm² mounting pad for collector
- (2) FR4 PCB; 6 cm² copper mounting pad for collector (3) FR4 PCB; 1 cm² copper mounting pad for collector
- (4) Standard footprint

Power derating curves Fig. 1.

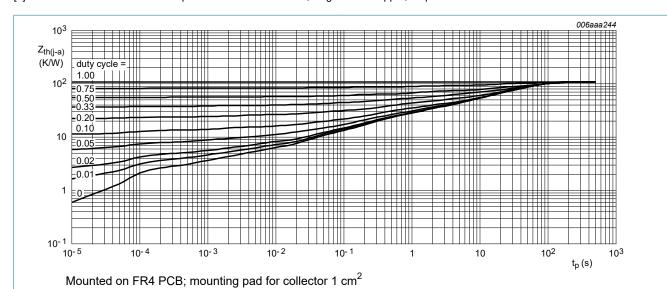
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9. Thermal characteristics

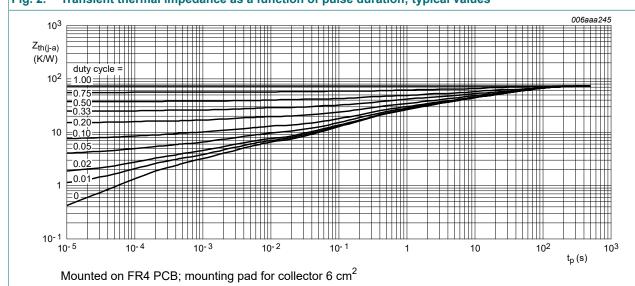
Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|---|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | thermal resistance from junction to ambient in free air [2] | [1] | - | - | 225 | K/W |
| | | | [2] | - | - | 125 | K/W |
| | | | [3] | - | - | 90 | K/W |
| | | | [4] | - | - | 80 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | - | 16 | K/W |

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm². Device mounted on a ceramic printed-circuit board 7 cm², single-sided copper, tin-plated.



Transient thermal impedance as a function of pulse duration; typical values Fig. 2.



Transient thermal impedance as a function of pulse duration; typical values

20 V, 3 A PNP low VCEsat (BISS) transistor

10. Characteristics

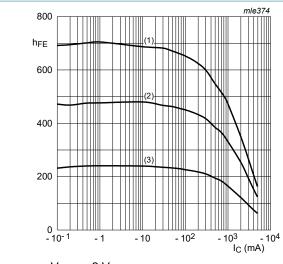
Table 7. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|---|--|-----|------|-----|------|------|
| I _{CBO} | collector-base cut-off | V _{CB} = -20 V; I _E = 0 A | | - | - | -100 | nA |
| | current | V _{CB} = -20 V; I _E = 0 A; T _j = 150 °C | | - | - | -50 | μΑ |
| I _{CES} | collector-emitter cut-off current | V _{CE} = -20 V; V _{BE} = 0 V | | - | - | -100 | nA |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A | | - | - | -100 | nA |
| h _{FE} | DC current gain | V _{CE} = -2 V; I _C = -0.1 A | | 220 | - | - | |
| | | V _{CE} = -2 V; I _C = -0.5 A | | 220 | - | - | |
| | | V _{CE} = -2 V; I _C = -1 A | [1] | 200 | - | - | |
| | | V _{CE} = -2 V; I _C = -2 A | [1] | 150 | - | - | |
| | | V _{CE} = -2 V; I _C = -3 A | [1] | 100 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = -0.5 A; I _B = -50 mA | | - | - | -70 | mV |
| | | I _C = -1 A; I _B = -50 mA | | - | - | -130 | mV |
| | | I _C = -2 A; I _B = -100 mA | | - | - | -230 | mV |
| | | I _C = -3 A; I _B = -300 mA | [1] | - | - | -300 | mV |
| R _{CEsat} | collector-emitter saturation resistance | | [1] | - | 90 | 105 | mΩ |
| V _{BEsat} | base-emitter saturation | I _C = -2 A; I _B = -100 mA | | - | - | -1.1 | V |
| | voltage | I _C = -3 A; I _B = -300 mA | [1] | - | - | -1.2 | V |
| V_{BEon} | base-emitter turn-on voltage | V _{CE} = -2 V; I _C = -1 A | | -1.1 | - | - | V |
| f _T | transition frequency | V _{CE} = -5 V; I _C = -100 mA; f = 100 MHz | | 100 | - | - | MHz |
| C _c | collector capacitance | V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz | | - | - | 50 | pF |

^[1] Pulsed test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$

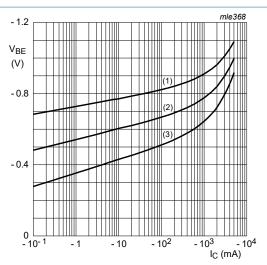
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$$V_{CE} = -2 V$$

$$(2) T_{amb} = 25 °C$$

Fig. 4. DC current gain as a function of collector current; typical values



$$V_{CF} = -2 V$$

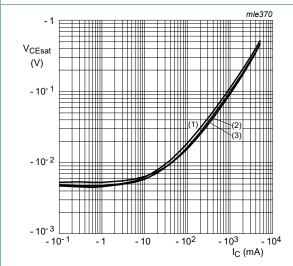
$$V_{CE} = -2 V$$

(1) $T_{amb} = -55 °C$
(2) $T_{amb} = 25 °C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



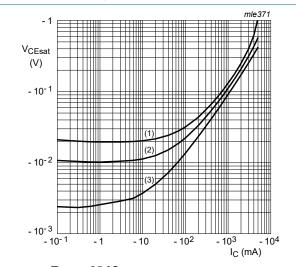
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

(1)
$$I_C/I_B = 100$$

(2)
$$I_C/I_B = 50$$

(3)
$$I_C/I_B = 10$$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

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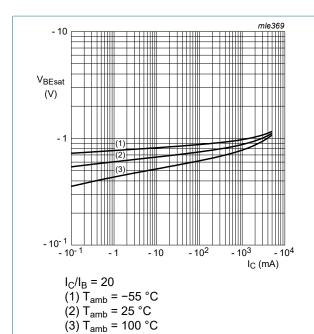
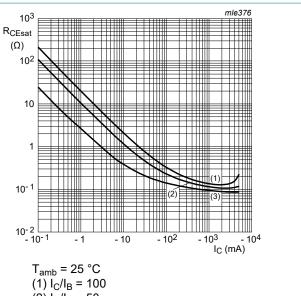
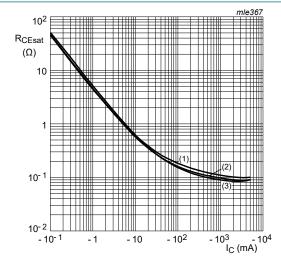


Fig. 8. Base-emitter saturation voltage as a function of Fig. 9. collector current; typical values



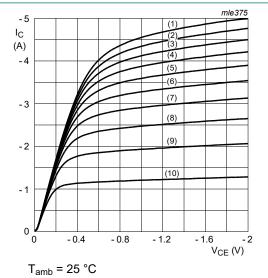
(2) $I_C/I_B = 50$ (3) $I_C/I_B = 10$

Equivalent on-resistance as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 10. Equivalent on-resistance as a function of collector current; typical values



(1) $I_B = -25 \text{ mA}$ $(2) I_B = -22.5 \text{ mA}$ (3) $I_B = -20 \text{ mA}$ $(4) I_B = -17.5 \text{ mA}$ $(5) I_B = -15 \text{ mA}$ (6) $I_B = -12.5 \text{ mA}$ (7) $I_B = -10 \text{ mA}$ (8) $I_B = -7.5 \text{ mA}$ (9) $I_B = -5 \text{ mA}$ $(10)^{-1}I_B = -2.5 \text{ mA}$

Fig. 11. Collector current as a function of collectoremitter voltage; typical values

20 V, 3 A PNP low VCEsat (BISS) transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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12. Package outline

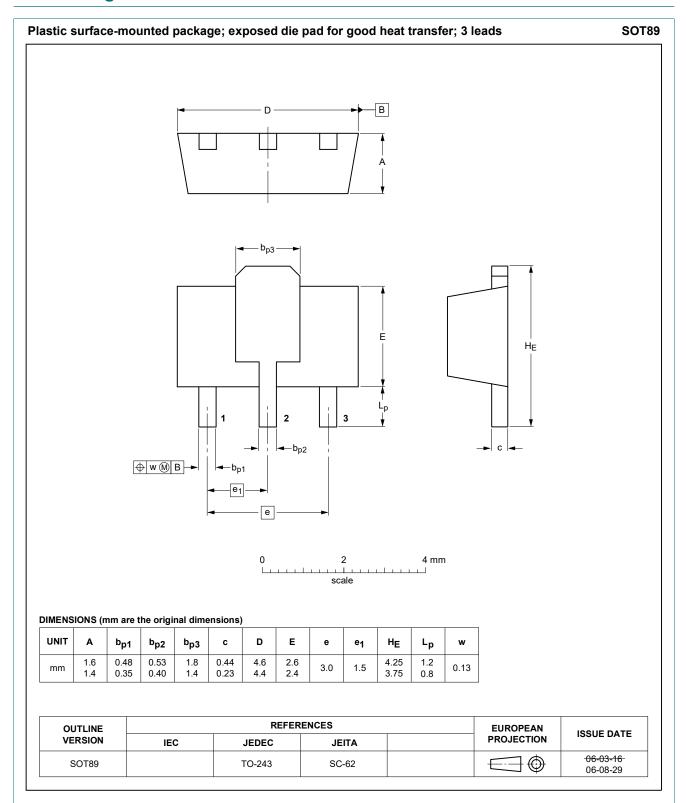
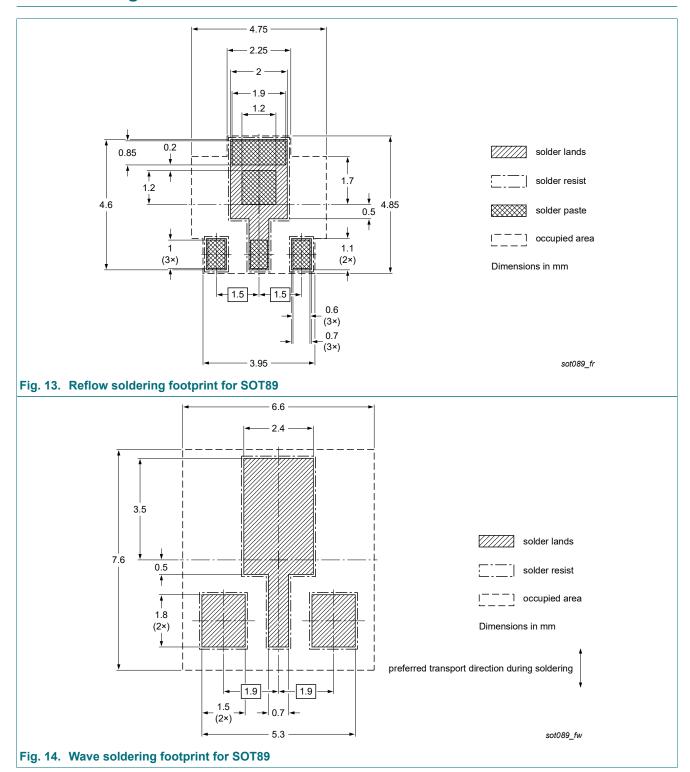


Fig. 12. Package outline SOT89

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13. Soldering



Product data sheet

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14. Revision history

Table 8. Revision history

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|------------------------|---|---|---------------|---------------|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | |
| PBSS5320X v.3 | 20190527 | Product data sheet | - | PBSS5320X v.2 | | |
| Modifications: | The format of Nexperia. | Characteristics: V _{BEsat} corrected from typical to maximum. The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. | | | | |
| PBSS5320X v.2 | 20041104 | Product data sheet | - | PBSS5320X v.1 | | |
| PBSS5320X v.1 | 20031127 | Product data sheet | - | - | | |

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15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
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